Old Company Name in Catalogs and Other Documents

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Renesas Electronics website: http://www.renesas.com

April 1st, 2010 Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

Send any inquiries to http://www.renesas.com/inquiry.

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RENESAS

RJK2006DPJ, RJK2006DPE, RJK2006DPF

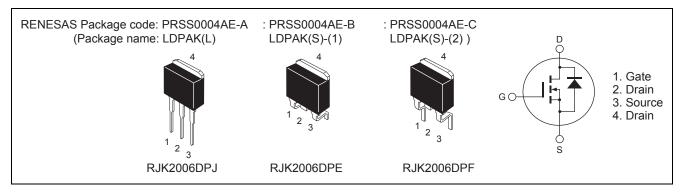
Silicon N Channel MOS FET High Speed Power Switching

> REJ03G0512-0200 Rev.2.00 Nov 19, 2009

Features

- Low on-resistance
- Low leakage current
- High speed switching

Outline



Absolute Maximum Ratings

			$(Ta = 25^{\circ}C)$
ltem	Symbol	Ratings	Unit
Drain to Source voltage	V _{DSS}	200	V
Gate to Source voltage	V _{GSS}	±30	V
Drain current	ID	40	A
Drain peak current	Note1 D (pulse)	100	А
Body-Drain diode reverse Drain current	I _{DR}	40	А
Body-Drain diode reverse Drain peak current	Note1 DR (pulse)	100	А
Avalanche current	I _{AP} ^{Note3}	27	А
Avalanche energy	E _{AR} ^{Note3}	48.6	mJ
Channel dissipation	Pch Note2	100	W
Channel to case thermal impedance	θch-c	1.25	°C/W
Channel temperature	Tch	150	٥°
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. PW \leq 10 μ s, duty cycle \leq 1%

2. Value at Tc = 25°C

3. STch = 25°C, Tch \leq 150°C

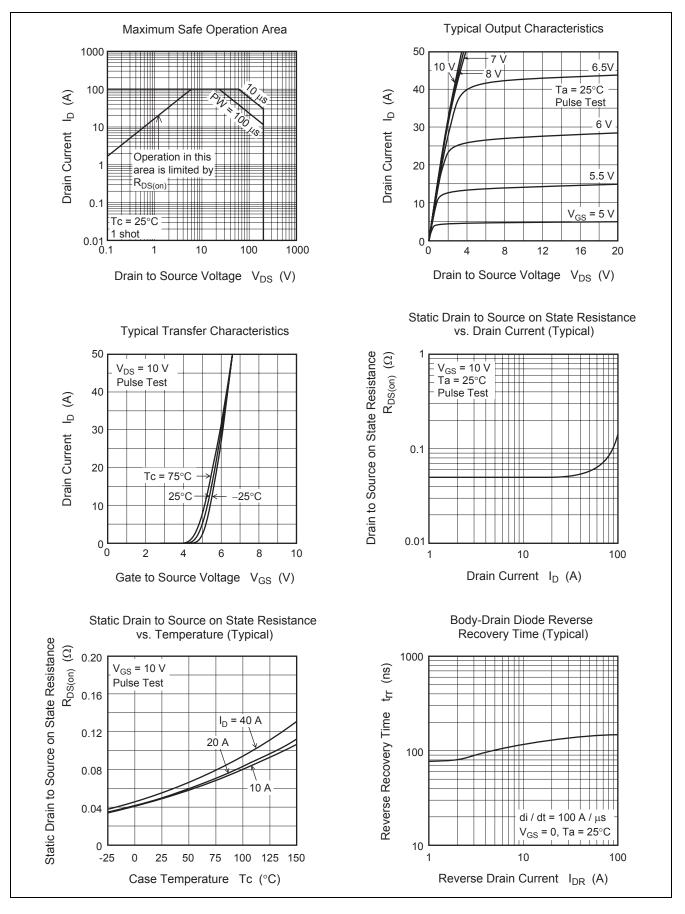
Electrical Characteristics

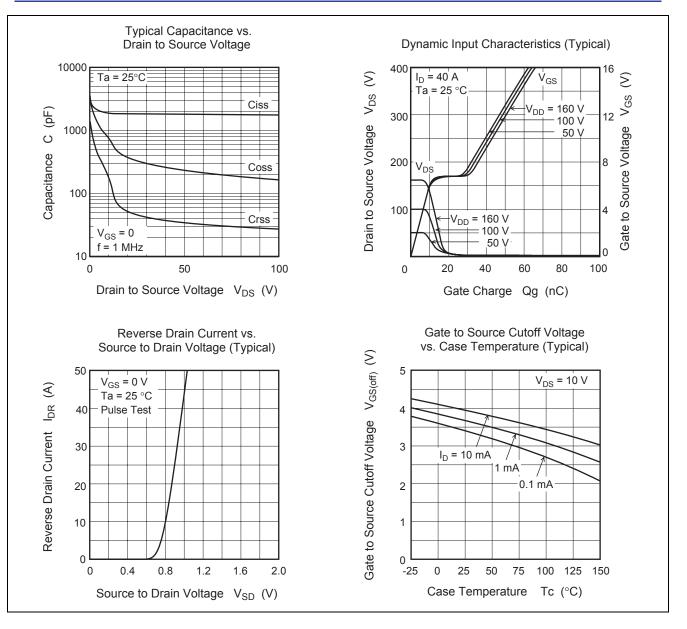
						$(Ta = 25^{\circ}C)$
Item	Symbol	Min	Тур	Max	Unit	Test conditions
Drain to Source breakdown voltage	V _{(BR)DSS}	200	—		V	I _D = 10 mA, V _{GS} = 0
Zero Gate voltage drain current	I _{DSS}	_	—	1	μA	V _{DS} = 200 V, V _{GS} = 0
Gate to Source leak current	I _{GSS}		_	±0.1	μΑ	V_{GS} = ±30 V, V_{DS} = 0
Gate to Source cutoff voltage	V _{GS(off)}	3.0	_	4.5	V	V _{DS} = 10 V, I _D = 1 mA
Forward transfer admittance	y _{fs}	15	26		S	I_D = 20 A, V_{DS} = 10 V ^{Note4}
Static Drain to Source on state resistance	R _{DS(on)}		0.052	0.059	Ω	I_D = 20 A, V_{GS} = 10 V^{Note4}
Input capacitance	Ciss	_	1800		pF	V _{DS} = 25 V V _{GS} = 0 f = 1 MHz
Output capacitance	Coss	_	330	_	pF	
Reverse transfer capacitance	Crss		43		pF	
Turn-on delay time	t _{d(on)}	_	30	—	ns	$I_D = 20 \text{ A}$ $V_{GS} = 10 \text{ V}$ $R_L = 5 \Omega$ $Rg = 10 \Omega$
Rise time	tr		180		ns	
Turn-off delay time	t _{d(off)}		85		ns	
Fall time	t _f		100		ns	
Total Gate charge	Qg		43		nC	V _{DD} = 160 V V _{GS} = 10 V I _D = 40 A
Gate to Source charge	Qgs		11		nC	
Gate to Drain charge	Qgd		20		nC	
Body-Drain diode forward voltage	V _{DF}		1.0	1.5	V	$I_F = 40 \text{ A}, V_{GS} = 0^{\text{Note4}}$
Body-Drain diode reverse recovery time	t _{rr}		150	—	ns	I _F = 40 A, V _{GS} = 0 di _F /dt = 100 A/μs
Body-Drain diode reverse recovery	Qrr	_	0.8	—	μC	
charge						

Notes: 4. Pulse test

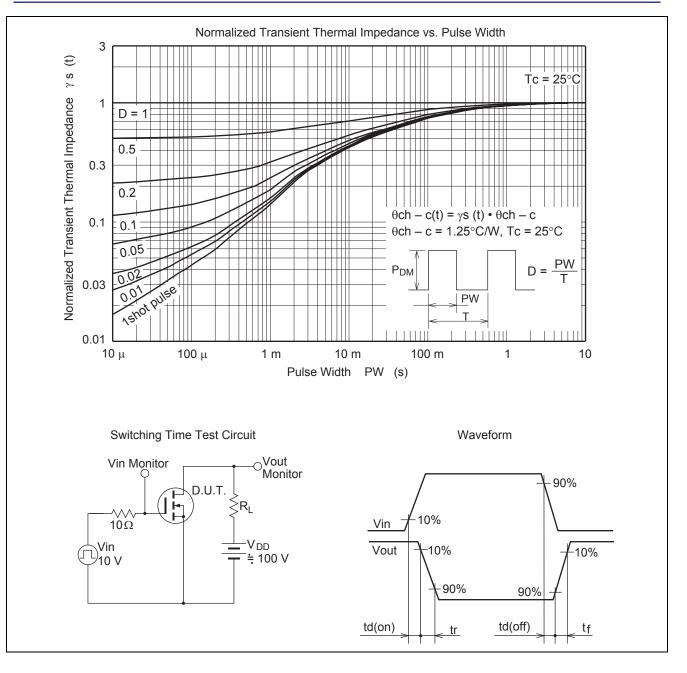


Main Characteristics



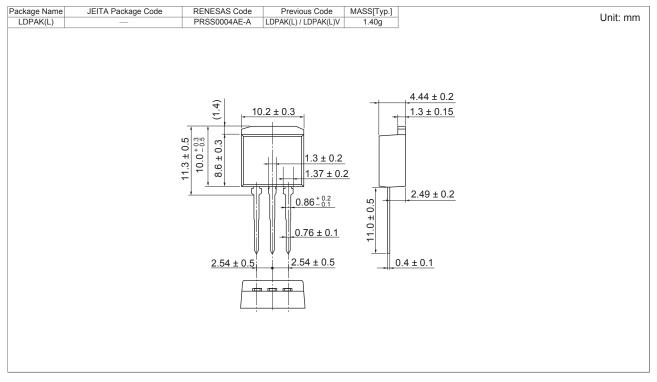


RJK2006DPJ, RJK2006DPE, RJK2006DPF

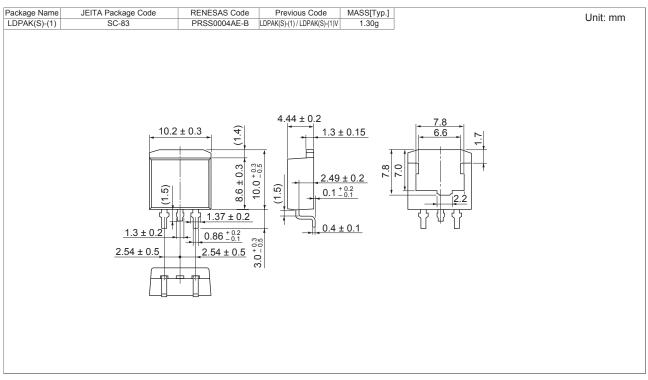


Package Dimensions

• RJK2006DPJ



• RJK2006DPE



• RJK2006DPF

ackage Name	JEITA Package Code	RENESAS Code	Previous Code MASS[Typ.]	Unit: mm
DPAK(S)-(2)		PRSS0004AE-C	LDPAK(S)-(2) / LDPAK(S)-(2)V 1.35g	Unit. min
	1.3 ± 0.2 2.54 ± 0.5	± 0.3 (7) (7) (7) (7) (7) (7) (7) (7)	$\begin{array}{c} 4.44 \pm 0.2 \\ \hline & 1.3 \pm 0.15 \\ \hline & 2.49 \pm 0.2 \\ \hline & 0.1 \stackrel{+0.2}{\longrightarrow} \\ \hline & 0.4 \pm 0.1 \end{array}$	

Ordering Information

Part No.	Quantity	Shipping Container
RJK2006DPE-00-J3	1000 pcs	Taping



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